

## INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

# TK32E12N1, ITK32E12N1

## • FEATURES

- Low drain-source on-resistance: RDs(on) ≤13.8mΩ. (VGs = 10 V)
- Enhancement mode:

Vth =2.0 to 4.0V (VDs = 10 V, ID=0.5mA)

- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

Switching Voltage Regulators

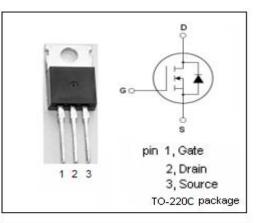
#### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

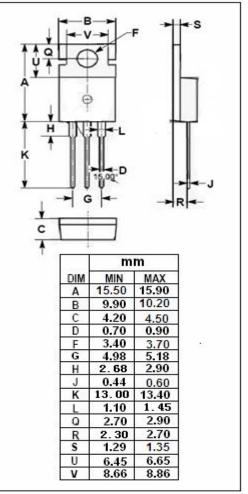
SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	120	V				
V <sub>GS</sub>	Gate-Source Voltage	±20	V				
ID	Drain Current-Continuous	60	A				
I <sub>DM</sub>	Drain Current-Single Pulsed	110	A				
PD	Total Dissipation @Tc=25°C	98	W				
Tj	Max. Operating Junction Temperature	150	°C				
T <sub>stg</sub>	Storage Temperature	-55~150	°C				

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT		
Rth(ch-c)	Channel-to-case thermal resistance	1.27	°C/W		
Rth(ch-a)	Rth(ch-a) Channel-to-ambient thermal resistance		°C/W		

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#### isc website: www.iscsemi.cn



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#### **ELECTRICAL CHARACTERISTICS**

 $T_{\text{C}}\text{=}25^{\circ}\!\!\!\mathrm{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =10mA	120			v
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =10V; I <sub>D</sub> =0.5mA	2.0		4.0	v
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =16A			13.8	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V			±0.1	μA
loss	Drain-Source Leakage Current	V <sub>DS</sub> =120V; V <sub>GS</sub> = 0V			10	μA
$V_{\text{SDF}}$	Diode forward voltage	I <sub>DR</sub> =32A, V <sub>GS</sub> = 0 V			1.2	v

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